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# LM2904,LM358/LM358A,LM258/ LM258A

# **Dual Operational Amplifier**

### **Features**

- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range: LM258/LM258A, LM358/LM358A: 3V~32V (or ±1.5V ~ 16V)

LM2904 :  $3V \sim 26V$  (or  $\pm 1.5V \sim 13V$ )

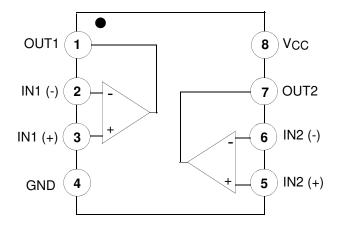
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V DC to Vcc -1.5V DC
- Power Drain Suitable for Battery Operation.

### **Description**

The LM2904,LM358/LM358A, LM258/LM258A consist of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltage. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. Application areas include transducer amplifier, DC gain blocks and all the conventional OP-AMP circuits which now can be easily implemented in single power supply systems.

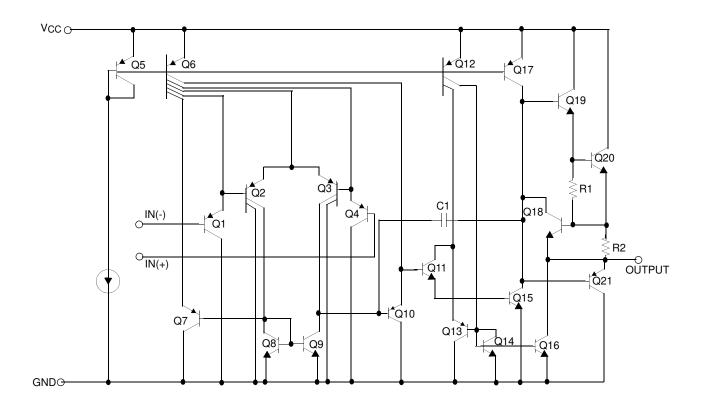


### **Internal Block Diagram**



# **Schematic Diagram**

(One section only)



# **Absolute Maximum Ratings**

Parameter	Symbol	LM258/LM258A	LM358/LM358A	LM2904	Unit
Supply Voltage	Vcc	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	VI(DIFF)	32	32	26	V
Input Voltage	VI	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND VCC≤15V, TA = 25°C(One Amp)	-	Continuous	Continuous	Continuous	-
Operating Temperature Range	TOPR	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Maximun Junction Temperature	TJ(MAX)	+150	+150	+150	°C
Storage Temperature Range	Tstg	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C

# **Electrical Characteristics**

 $(V_{CC} = 5.0V, V_{EE} = GND, T_A = 25^{\circ}C, unless otherwise specified)$ 

Devemeter	Cymahal	Conditions		LM258			LM358			LM2904			11
Parameter	Symbol	Conai	Conditions		Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$VCM = 0V$ $-1.5V$ $VO(P) = 1.6$ $RS = 0\Omega$		-	2.9	5.0	-	2.9	7.0	-	2.9	7.0	mV
Input Offset Current	lio	-		-	3	30	-	5	50	-	5	50	nA
Input Bias Current	IBIAS	-		-	45	150	-	45	250	-	45	250	nA
Input Voltage Range	V <sub>I(R)</sub>	VCC = 30V (LM2904, V		0	-	VCC -1.5	0	-	VCC -1.5	0	-	VCC -1.5	V
Supply Current	Icc	$RL = \infty$ , $VC$ (LM2904, Y		1	0.8	2.0	-	0.8	2.0	-	8.0	2.0	mA
Supply Surrent	100	$R_L = \infty$ , $V_C$	CC = 5V	1	0.5	1.2	-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	Gv	$V_{CC} = 15V_{RL} = 2k\Omega$ $V_{O(P)} = 1V_{RL}$		50	100	-	25	100	-	25	100	-	V/mV
	VO(H)	VCC=30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Output Voltage Swing		(VCC =26V for LM2904)	RL= 10kΩ	27	28	-	27	28	-	23	24	-	٧
	V <sub>O(L)</sub>	VCC = 5V,	R <sub>L</sub> = 10kΩ	-	5	20	-	5	20		5	20	mV
Common-Mode Rejection Ratio	CMRR	-		70	85	-	65	80	-	50	80	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	50	100	-	dB
Channel Separation	CS	f = 1kHz to (Note1)	20kHz	-	120	-	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	-		-	40	60	-	40	60	-	40	60	mA
	ISOURCE	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V, V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		20	30	-	20	30	-	20	30	-	mA
Output Current	JOINIZ	VCC = 15V	VI(+) = 0V, VI(-) = 1V, VCC = 15V, VO(P) = 2V		15	-	10	15	-	10	15	-	mA
	ISINK $VI(+) = 0V, VI(-) = VCC = 15V, VO(P) = 200mV$		<b>'</b> , ``	12	100	-	12	100	-	-	-	-	μА
Differential Input Voltage	V <sub>I</sub> (DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	٧

#### Note:

<sup>1.</sup> This parameter, although guaranteed, is not 100% tested in production.

### **Electrical Characteristics** (Continued)

(VCC= 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C  $\leq$  TA  $\leq$  +85°C for the LM258; and the 0°C  $\leq$  TA  $\leq$  +70°C for the LM358; and the -40°C  $\leq$  TA  $\leq$  +85°C for the LM2904

Dawamastan	Oursels of	Conditions			LM25	8		LM35	8	L	l lm!s		
Parameter	Symbol	Cona	itions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$V_{CM} = 0V$ to $V_{CC}$ -1.5V $V_{O(P)} = 1.4V$ , $R_{S} = 0\Omega$		-	-	7.0	-	-	9.0	-	-	10.0	mV
Input Offset Voltage Drift	ΔVΙΟ/ΔΤ	$Rs = 0\Omega$		-	7.0	-	-	7.0	-	-	7.0	-	μV/°C
Input Offset Current	lio	-	-	-	-	100	-	-	150	-	45	200	nA
Input Offset Current Drift	ΔΙ <sub>ΙΟ</sub> /ΔΤ	-	-	-	10	-	-	10	-	-	10	-	pA/°C
Input Bias Current	IBIAS	-		-	40	300	-	40	500	-	40	500	nA
Input Voltage Range	VI(R)	V <sub>CC</sub> = 30V (LM2904 , V <sub>CC</sub> = 26V)		0	-	VCC -2.0	0	-	VCC -2.0	0	-	VCC -2.0	٧
Large Signal Voltage Gain	Gv	$V_{CC} = 15V$ , $R_L = 2.0kΩ$ $V_{O(P)} = 1V$ to 11V		25	-	-	15	-	-	15	-	-	V/mV
		VCC=30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Output Voltage Swing	VO(H)	(VCC = 26V for LM2904)	R <sub>L</sub> =10kΩ	27	28	-	27	28	-	23	24	-	V
	V <sub>O(L)</sub>	VCC = 5V,	R <sub>L</sub> =10kΩ	-	5	20	-	5	20	-	5	20	mV
Output Current	ISOURCE	$V_{I(+)} = 1V,$ $V_{I(-)} = 0V,$ $V_{CC} = 15V,$ $V_{O(P)} = 2V$		10	30	-	10	30	-	10	30	-	mA
Output Ourient	ISINK	V <sub>I(+)</sub> = 0V, V <sub>I(-)</sub> = 1V, V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		5	8	-	5	9	-	5	9	-	mA
Differential Input Voltage	VI(DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	٧

# **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, TA = 25°C, unless otherwise specified)

Davamatav	Symbol Conditions				LM258	Α		Unit		
Parameter	Symbol	Condit	ions	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	VCM = 0V  to  V $VO(P) = 1.4V$		-	1.0	3.0	-	2.0	3.0	mV
Input Offset Current	lio	-		-	2	15	-	5	30	nA
Input Bias Current	IBIAS	-		-	40	80	-	45	100	nA
Input Voltage Range	V <sub>I(R)</sub>	VCC = 30V		0	-	VCC -1.5	0	-	VCC -1.5	V
Supply Current	loo	RL = ∞,VCC =	30V	-	0.8	2.0	-	0.8	2.0	mA
Supply Gullelli	Icc	RL = ∞, Vcc =	: 5V	-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	Gγ	$V_{CC} = 15V$ , $R_{L} = 2k\Omega$ $V_{O} = 1V$ to $11V$		50	100	-	25	100	-	V/mV
	Vou	Voc. 20V	$RL = 2k\Omega$	26	-	-	26		-	V
Output Voltage Swing	Vон	VCC = 30V	R <sub>L</sub> =10kΩ	27	28	-	27	28	-	V
	V <sub>O(L)</sub>	$VCC = 5V, RL=10k\Omega$		-	5	20	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-		70	85	-	65	85	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	dB
Channel Separation	CS	f = 1kHz to 20	kHz (Note1)	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	-		-	40	60	-	40	60	mA
	ISOURCE	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2V$		20	30	-	20	30	-	mA
Output Current	lowik	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		10	15	-	10	15	-	mA
	Isink	$V_{in +} = 0V, V_{in (-)} = 1V$ $V_{O(P)} = 200mV$		12	100	-	12	100	-	μΑ
Differential Input Voltage	VI(DIFF)	-	-	-	Vcc	-	-	Vcc	V	

### Note:

<sup>1.</sup> This parameter, although guaranteed, is not 100% tested in production.

# **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C  $\leq$  TA  $\leq$  +85°C for the LM258A; and the 0°C  $\leq$  TA  $\leq$  +70°C for the LM358A

Parameter	Cymbol	Conditions			_M258	BA	L	Unit		
Farameter	Symbol	Cond			Тур.	Max.	Min.	Тур.	Max.	Oilit
Input Offset Voltage	VIO	$V_{CM} = 0V \text{ to}$ $V_{O(P)} = 1.4V$		-	-	4.0	-	-	5.0	mV
Input Offset Voltage Drift	ΔV10/ΔΤ		-	-	7.0	15	-	7.0	20	μV/°C
Input Offset Current	lιο		-	-	-	30	-	-	75	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ		-	-	10	200	-	10	300	pA/°C
Input Bias Current	IBIAS		-	-	40	100	-	40	200	nA
Input Common-Mode Voltage Range	V <sub>I(R)</sub>	VCC = 30V		0	-	Vcc -2.0	0	-	Vcc -2.0	V
	Vous	VO(H) VCC = 30V	$R_L = 2k\Omega$	26	-	-	26	-	-	V
Output Voltage Swing	<b>V</b> O(H)		$R_L = 10k\Omega$	27	28	-	27	28	-	V
	V <sub>O(L)</sub>	Vcc = 5V, F	RL=10kΩ	-	5	20	-	5	20	mV
Large Signal Voltage Gain	Gv	$V_{CC} = 15V, R_{L}=2.0k\Omega$ $V_{O(P)} = 1V \text{ to } 11V$		25	-	-	15	-	-	V/mV
Output Current	ISOURCE	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		10	30	-	10	30	-	mA
Output Ourient	ISINK $V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2V$			5	9	ı	5	9	1	mA
Differential Input Voltage	V <sub>I</sub> (DIFF)		-	-	-	Vcc	-	-	Vcc	V

# **Typical Performance Characteristics**

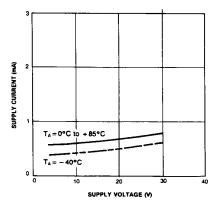


Figure 1. Supply Current vs Supply Voltage

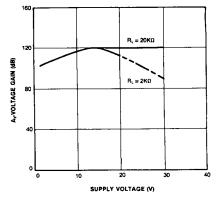


Figure 2. Voltage Gain vs Supply Voltage

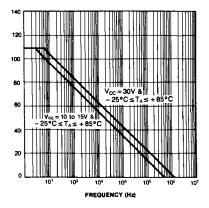


Figure 3. Open Loop Frequency Response

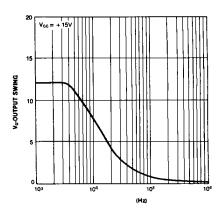


Figure 4. Large Signal Output Swing vs Frequency

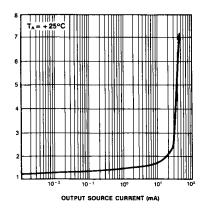


Figure 5. Output Characteristics vs Current Sourcing

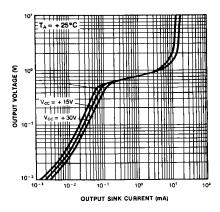


Figure 6. Output Characteristics vs Current Sinking

# **Typical Performance Characteristics** (Continued)

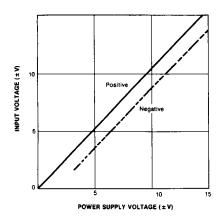


Figure 7. Input Voltage Range vs Supply Voltage

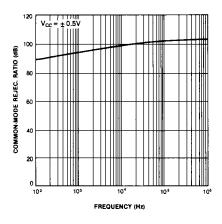


Figure 8. Common-Mode Rejection Ratio

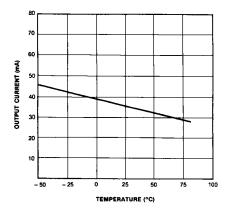


Figure 9. Output Current vs Temperature (Current Limiting)

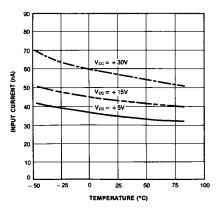


Figure 10. Input Current vs Temperature

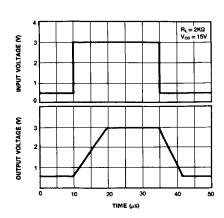


Figure 11. Voltage Follower Pulse Response

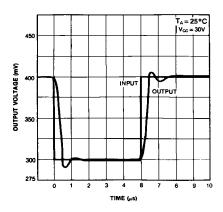
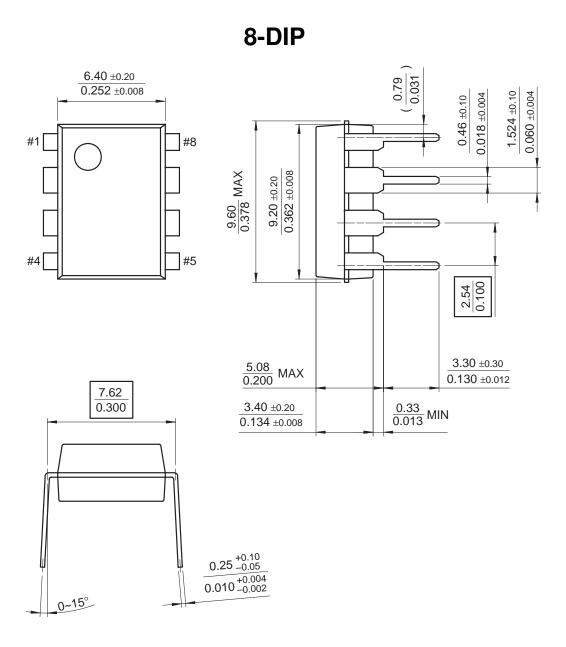


Figure 12. Voltage Follower Pulse Response (Small Signal)

# **Mechanical Dimensions**

### **Package**

### **Dimensions in millimeters**

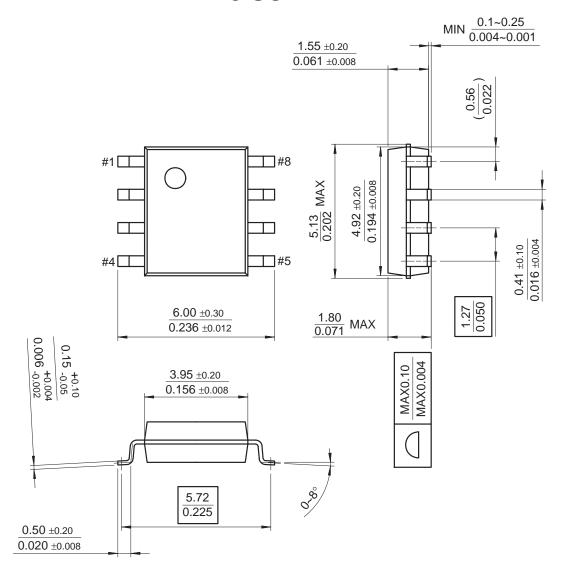


### **Mechanical Dimensions** (Continued)

### **Package**

#### **Dimensions in millimeters**

# 8-SOP



# **Ordering Information**

Product Number	Package	Operating Temperature
LM358N	8-DIP	
LM358AN	Q-DIF	0 ~ +70°C
LM358M	8-SOP	0 4 +70 0
LM358AM	- 0-3OF	
LM2904N	8-DIP	-40 ∼ +85°C
LM2904M	8-SOP	-40 ~ +83 C
LM258N	8-DIP	
LM258AN	Q-DIF	-25 ∼ +85°C
LM258M	8-SOP	-25 · +65 C
LM258AM	0-3OF	

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